

SE1AD THRU SE1MD

SURFACE MOUNT HIGH EFFICIENT RECTIFIER

Reverse Voltage - 50 to 1000 V

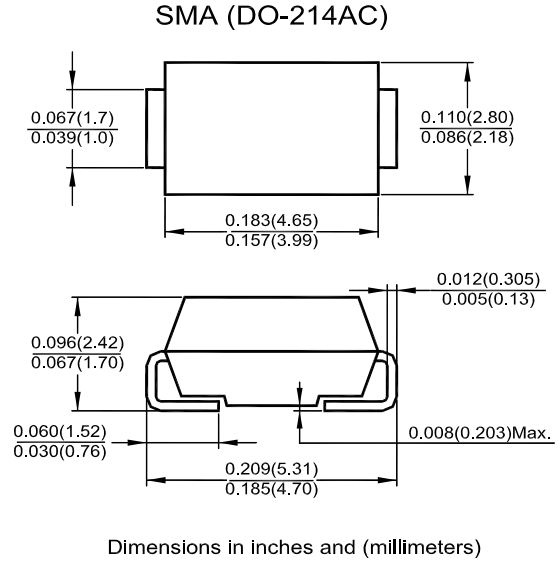
Forward Current - 1 A

Features

- High current capability
- High surge current capability
- High reliability
- Low reverse current
- Low forward voltage drop
- Fast switching for high efficiency

Mechanical Data

- **Case:** SMA (DO-214AC) molded plastic
- **Epoxy:** UL 94V-0 rate flame retardant
- **Lead:** Lead formed for surface mount
- **Polarity:** color band denotes cathode end
- **Mounting position:** Any



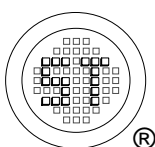
Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	SE1AD	SE1BD	SE1DD	SE1ED	SE1GD	SE1JD	SE1KD	SE1MD	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Current $T_a = 55\text{ }^\circ\text{C}$	$I_{F(AV)}$	1								A
Maximum Peak Forward Surge Current, 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	30								A
Maximum Forward Voltage at $I_F = 1\text{ A}$	V_F	1.1			1.7		2.2		V	
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 100\text{ }^\circ\text{C}$	I_R	5				50				μA
Maximum Reverse Recovery Time ¹⁾	t_{rr}	50			75			ns		
Typical Junction Capacitance ²⁾	C_j	50								pF
Junction and Storage Temperature Range	T_j, T_{stg}	- 65 to + 150								$^\circ\text{C}$

¹⁾ Reverse recovery test conditions: $I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$

²⁾ Measured at 1 MHz and applied reverse voltage of 4 V



SEMTECH ELECTRONICS LTD.
Subsidiary of Sino-Tech International (BVI) Limited



SE1AD THRU SE1MD

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

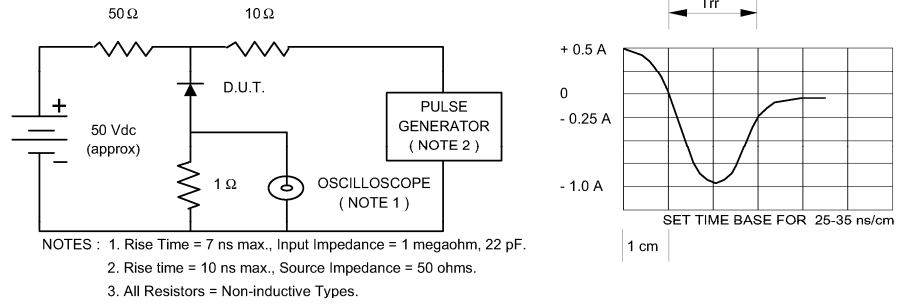


FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

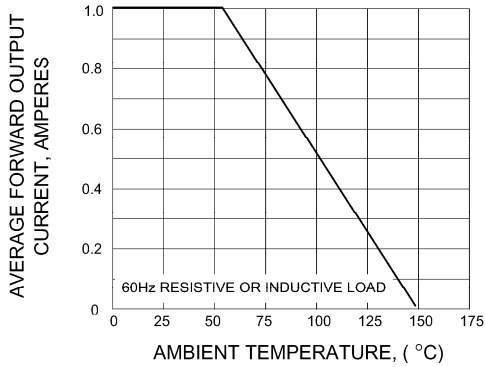


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

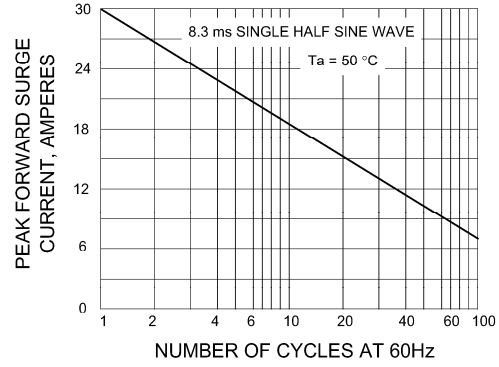


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

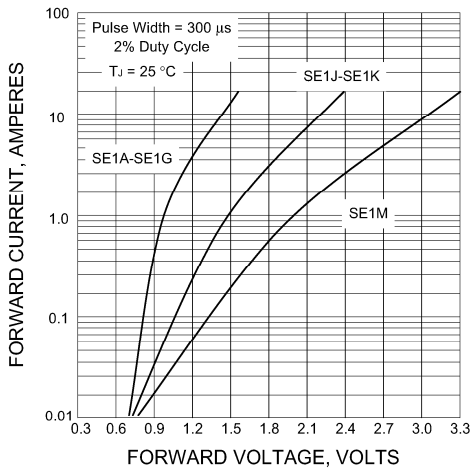
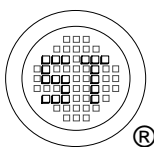
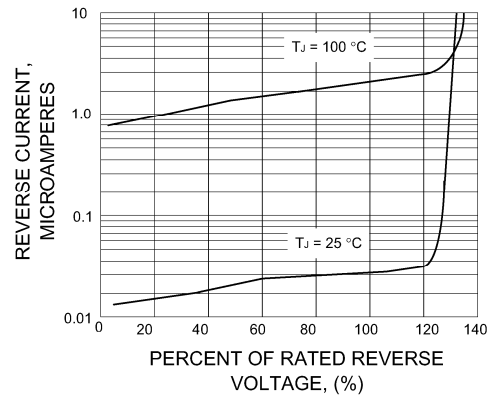


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



SEMTECH ELECTRONICS LTD.
 Subsidiary of Sino-Tech International (BVI) Limited

